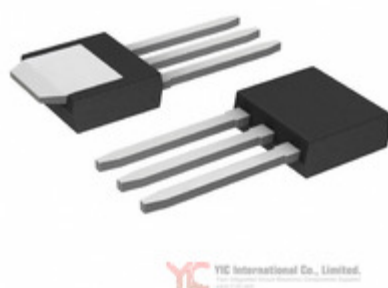

	<p>NTD6600N-1G</p>
	<p>Hersteller-Teilenummer: NTD6600N-1G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 100V 12A IPAK</p>
<p>Image may be representation. See specs for product details.</p>	<p>Datenblätter:  NTD6600N-1G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 5000 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NTD6600N-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.28W (Ta), 56.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Ta)
Rds On (Max) @ Id, Vgs	146 mOhm @ 6A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	700pF @ 25V
Verpackung	Tube



















































NTD6600N-1G ist neu im Original, Suche NTD6600N-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD6600N-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD6600N-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD6600NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p>NTD6600G ON NTD6600G ON</p>	 <p>NTD6600N AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p>NTD6600N-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A IPAK</p>
 <p>NTD65N03RT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A DPAK</p>	 <p>NTD70N03 ON NTD70N03 ON</p>	 <p>NTD6600NT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p>NTD6N20ET4G ON ON SOT-252</p>

heiße Teile

Mehr

 NTD6414AN-1G	 NTD6414ANT4G	 NTD6414AUG	 NTD6415AN	 NTD6415AN-1G
 NTD6415ANL	 NTD6415ANLT4G	 NTD6415ANT4G	 NTD6416AN	 NTD6416AN-1G
 NTD6416ANG	 NTD6416ANL	 NTD6416ANL-1G	 NTD6416ANLT4G	 NTD6416ANT4G
 NTD65N03G	 NTD65N03R-001	 NTD65N03R-035	 NTD65N03R-1G	 NTD65N03R-35G
 NTD65N03RG	 NTD65N03RT4G	 NTD6600G	 NTD6600N	 NTD6600N-001
 NTD6600NT4	 NTD6600NT4G	 NTD70N03	 NTD70N03R	 NTD70N03R-001
 NTD70N03R-1	 NTD70N03R-1G	 NTD70N03RG	 NTD70N03RT4	 NTD70N03RT4G
 NTD70N03TR4	 NTD78N03	 NTD78N03-001	 NTD78N03-035	 NTD78N03-1
 NTD78N03-1G	 NTD78N03-35G	 NTD78N03R-001	 NTD78N03R-1G	 NTD78N03RT4G
 NTD78N03T4	 NTD78N03T4G	 NTD80N02	 NTD80N02-001	 NTD80N02-1

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited